

## +5 Volt, Serial Input, Dual 12-Bit DAC

AD8522

#### **FEATURES**

Complete Dual 12-Bit DAC
No External Components
+5 V Single-Supply Operation ±10%
4.095 V Full Scale (1 mV/LSB)
Buffered Voltage Outputs
Low Power: 5 mW/DAC
Space Saving 1.5 mm Height SO-14 Package

APPLICATIONS
Digitally Controlled Calibration
Servo Controls
Process Control Equipment
Computer Peripherals
Portable Instrumentation
Cellular Base Stations Voltage Adjustment

#### GENERAL DESCRIPTION

The AD8522 is a complete dual 12-bit, single-supply, voltage output DAC in a 14-pin DIP, or SO-14 surface mount package. Fabricated in a CBCMOS process, features include a serial digital interface, onboard reference, and buffered voltage output. Ideal for +5 V-only systems, this monolithic device offers low cost and ease of use, and requires no external components to realize the full performance of the device.

The serial digital interface allows interfacing directly to numerous microcontroller ports, with a simple high speed, three-wire data, clock, and load strobe format. The 16-bit serial word contains the 12-bit data word and DAC select address, which is decoded internally or can be decoded externally using  $\overline{\text{LDA}}$ ,  $\overline{\text{LDB}}$ 

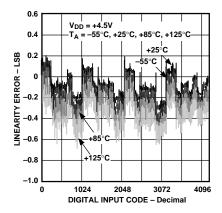
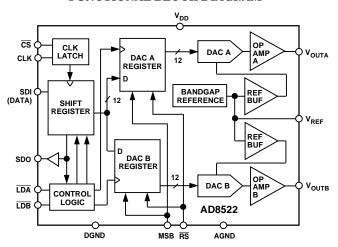


Figure 1. Linearity Error vs. Digital Code & Temperature

#### REV. A

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#### FUNCTIONAL BLOCK DIAGRAM

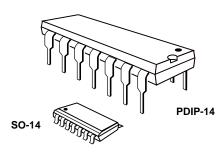


inputs. A serial data output allows the user to easily daisy-chain multiple devices in conjunction with a chip select input. A reset  $\overline{\text{RS}}$  input sets the outputs to zero scale or midscale, as determined by the input MSB.

The output 4.095 V full scale is laser trimmed to maintain accuracy over the operating temperature range of the device, and gives the user an easy-to-use one-millivolt-per-bit resolution. A 2.5 V reference output is also available externally for other data acquisition circuitry, and for ratiometric applications. The output buffers are capable of driving  $\pm 5~\text{mA}.$ 

The AD8522 is available in the 14-pin plastic DIP and low profile 1.5 mm SOIC-14 packages.

#### PACKAGE TYPES AVAILABLE



# 

Parameter	Symbol	Condition	Min	Тур	Max	Units
STATIC PERFORMANCE						
Resolution <sup>1</sup>	N		12	. 0 "		Bits
Relative Accuracy	INL	36	-1.5	$\pm 0.5$	+1.5	LSB
Differential Nonlinearity	DNL	Monotonic	-1	$\pm 0.5$	+1	LSB
Zero-Scale Error	V <sub>ZSE</sub>	$Data = 000_{H}$	4.070	+0.5	+3	mV
Full-Scale Voltage <sup>2</sup> Full-Scale Tempco <sup>2, 3</sup>	$V_{FS}$	$Data = FFF_{H}$	4.079	$4.095 \\ \pm 15$	4.111	Volts ppm/°C
MATCHING PERFORMANCE	TCV <sub>FS</sub>			±13		ppiii/ C
Linearity Matching Error	$\Delta V_{FS}A/B$			±1		LSB
ANALOG OUTPUT						
Output Current	I <sub>OUT</sub>	Data = $800_{H}$ , $\Delta V_{OUT} \le 3$ LSB			$\pm 5$	mA
Load Regulation at Half-Scale	LD <sub>REG</sub>	$R_L = 402 \Omega \text{ to } \infty, \text{ Data} = 800_H$		1	3	LSB
Capacitive Load <sup>3</sup>	$C_L$	No Oscillation		500		pF
REFERENCE OUTPUT						
Output Voltage	$V_{ m REF}$		2.484	2.500	2.516	V
Output Source Current <sup>4</sup>	$I_{REF}$	$\Delta V_{REF} < 18 \text{ mV}$			5	mA
Line Rejection	$LN_{REJ}$			0.025	0.08	%/V
Load Regulation	$LD_{REG}$	$I_{REF} = 0$ to 5 mA, Data = $800_H$		0.025	0.1	%/mA
LOGIC INPUTS & OUTPUTS						
Logic Input Low Voltage	V <sub>IL</sub>				0.8	V
Logic Input High Voltage	$V_{IH}$		2.4		10	V
Input Leakage Current	I <sub>IL</sub>				10	μA
Input Capacitance <sup>3</sup>	$C_{IL}$	I 1.C A			10	pF V
Logic Output Voltage Low	V <sub>OL</sub>	$I_{OL} = 1.6 \text{ mA}$	3.5		0.4	V
Logic Output Voltage High TIMING SPECIFICATIONS <sup>3, 5</sup>	V <sub>OH</sub>	$I_{OH} = 400 \mu A$	3.3			V
			35			
Clock Width High Clock Width Low	t <sub>CH</sub>		35			ns
Load Pulse Width	$egin{array}{c} t_{ m CL} \ t_{ m LDW} \end{array}$		25			ns ns
Data Setup	t <sub>DS</sub>		10			ns
Data Betap Data Hold	t <sub>DH</sub>		20			ns
Clear Pulse Width	t <sub>CLRW</sub>		20			ns
Load Setup	t <sub>LD1</sub>		10			ns
Load Hold	t <sub>LD2</sub>		10			ns
Select	t <sub>CSS</sub>		30			ns
Deselect	$t_{CSH}$		30			ns
Clock to SDO Propagation Delay	$t_{PD}$		20	45	80	ns
AC CHARACTERISTICS <sup>3, 5</sup>						
Voltage Output Settling Time <sup>6</sup>	$egin{array}{c} t_{\mathrm{S}} \ C_{\mathrm{T}} \end{array}$	To ±1 LSB of Final Value		16		μs
Crosstalk	$C_{\mathrm{T}}$	Signal Measured at DAC Output,				
5 1 6 61 1		While Changing Opposite LDA/B		38		dB
DAC Glitch	Q	Half-Scale Transition		13		nV s
Digital Feedthrough	$D_{FT}$	Signal Measured at DAC Output,		0		
GUPPLU GULLP : STEPPLET		While Changing Data Without LDA/B		2		nV s
SUPPLY CHARACTERISTICS	_			0	_	
Positive Supply Current	$I_{DD}$	$V_{\rm DD} = 5.5 \text{ V}, V_{\rm IH} = 2.4 \text{ V or } V_{\rm IL} = 0.8 \text{ V}$		3	5	mA
Dames Dissipation 7	D	$V_{DD} = 5 \text{ V}, V_{IL} = 0 \text{ V}$		1	2	mA
Power Dissipation <sup>7</sup>	$P_{DISS}$	$V_{\rm DD} = 5 \text{ V}, V_{\rm IH} = 2.4 \text{ V or } V_{\rm IL} = 0.8 \text{ V}$		15	25 10	mW
Power Supply Sensitivity	PSS	$V_{DD} = 5 \text{ V}, V_{IL} = 0 \text{ V}$ $\Delta V_{DD} = \pm 5\%$		5 0.002	10 0.004	mW %/%
NOTES	100	7 A DD — 7 2 /0		0.002	0.004	/0//0

REV. A -2-

NOTES  $^{1}$ 1 LSB = 1 mV for 0 V to +4.095 V output range.  $^{2}$ Includes internal voltage reference error.  $^{3}$ These parameters are guaranteed by design and not subject to production testing.  $^{4}$ Very little sink current is available at the V<sub>REF</sub> pin. Use external buffer if setting up a virtual ground.  $^{5}$ All input control signals are specified with  $t_r = t_f = 5$  ns (10% to 90% of +5 V) and timed from a voltage level of 1.6 V.  $^{6}$ The settling time specification does not apply for negative going transitions within the last 6 LSBs of ground. Some devices exhibit double the typical settling time in this 6 LSB region.  $^{7}$ Power Dissipation is calculated  $I_{DD} \times 5$  V.

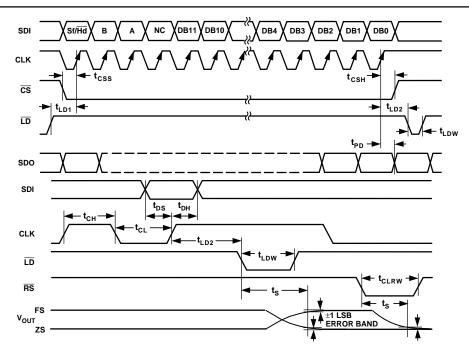


Figure 2. Timing Diagram

#### SERIAL INPUT REGISTER DATA FORMAT

Last															First
D0	D1	D2	D3	D4	D5	D6	D7	D8	D9	D10	D11	D12	D13	D14	D15
DB0	DB1	DB2	DB3	DB4	DB5	DB6	DB7	DB8	DB9	DB10	DB11	NC	A	В	Sf/Hd

**Table I. Truth Table** 

Data Word		Ext Pins	S			
Sf/Hd	В	A	LDA	LDB	DAC Register	
Hardware Load:						
L	X	X	↓	↓	Loads DACA + DACB with Data from SR	
L	X	X	↓	H	Loads DACA with Data from SR	
L	X	X	Н	↓	Loads DACB with Data from SR	
L	X	X	Н	Н	No Load	
Software Dec	code Load:					
Н	L	L	X	X	No Load	
Н	Н	L	↓ ↓	↓ ↓	Loads DACB with Data from SR, See Note 1 Below	
Н	Н	L	Н	Н	No Load	
Н	L	Н	↓ ↓	↓ ↓	Loads DACA with Data from SR, See Note 1 Below	
Н	L	Н	Н	Н	No Load	
Н	Н	Н	↓	↓	Loads DACA + DACB with Data from SR, See 1 Note Below	
Н	Н	Н	Н	Н	No Load	

#### NOTES

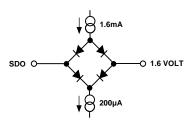


Figure 3. AC Timing SDO Pin Load Circuit

REV. A

 $<sup>^1</sup>$ In software mode  $\overline{LDA}$  and  $\overline{LDB}$  perform the same function. They can be tied together or the unused pin should be tied high.  $^2$ External Pins  $\overline{LDA}$  and  $\overline{LDB}$  should always be high when shifting Data into the shift register.

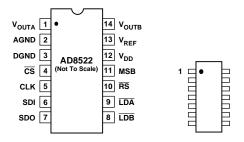
 $<sup>^{3} \!\! \</sup>downarrow$  symbol denotes negative transition.

#### PIN DESCRIPTION

Pin	Function
SDI CLK	Serial Data Input, input data loads directly into the shift register. Clock input, positive edge clocks data into shift register.
$\overline{CS}$	Chip Select, active low input. Prevents shift register loading when high. Does not affect $\overline{\text{LDA}}$ and $\overline{\text{LDB}}$ operation.
LDA/B	Load DAC register strobes, active low. Transfers shift register data to DAC register. See truth table for operation. Software decode feature only requires one $\overline{LD}$ strobe. Tie $\overline{LDA}$ and $\overline{LDB}$ together or use one of them with the other pin tied high.
SDO	Serial Data Output. Output of shift register, always active.
$\overline{RS}$	Resets DAC registers to condition determined by MSB pin. Active low input.
MSB	Digital input: High presets DAC registers to half scale $(800_H)$ ; Low clears all registers to zero $(000_H)$ , when $\overline{RS}$ is strobed to active low.
$V_{DD}$	Positive $+5$ V power supply input. Tolerance $\pm 10\%$ .
AGND	Analog Ground Input.
DGND	Digital Ground Input.
$V_{\text{REF}}$	Reference Voltage Output, 2.5 V nominal.
$V_{OUT\;A/B}$	DAC A/B voltage outputs, 4.095 V full scale, ±5 mA output.

#### PIN CONFIGURATION

#### 14-Pin Plastic DIP 14-Lead SO-14



**Table II. Truth Tables** 

RS	MSB	DAC Register Preset Register Activity
0	0	Asynchronously Resets DAC Registers to Zero
0	1	Asynchronously Presets DAC Registers to Half Scale (800 <sub>H</sub> )
1	X	None
<del>CS</del>	CLK	Shift Register Shift Register
1 0	X ↑	No Effect Shifts Register One Bit, SDO Outputs Data from 16 Clocks Earlier

#### **ABSOLUTE MAXIMUM RATINGS\***

$V_{DD}$ to DGND & AGND0.3 V, +7 V
Logic Inputs and Output to DGND $\dots$ -0.3 V, $V_{DD}$ + 0.3 V
$V_{OUT}$ to AGND0.3 V, $V_{DD}$ + 0.3 V
$V_{REF}$ to AGND0.3 V, $V_{DD}$ + 0.3 V
AGND to DGND0.3 V, $V_{DD}$
I <sub>OUT</sub> Short Circuit to GND or V <sub>DD</sub> 50 mA
Package Power Dissipation $(T_J \text{ max-}T_A)/\theta_{JA}$
Thermal Resistance, $\theta_{JA}$
14-Pin Plastic DIP Package (N-14)
14-Lead SOIC Package (SO-14) 120°C/W
Maximum Junction Temperature (T <sub>J</sub> max) 150°C
Operating Temperature Range40°C to +85°C
Storage Temperature Range65°C to +150°C
Lead Temperature (Soldering, 10 sec) +300°C

\*Stresses above those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. This is a stress rating only and functional operation of the device at these or any other conditions above those indicated in the operational sections of this specification is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

#### **ORDERING GUIDE**

Model	Temperature	Package	Package	
	Range	Description	Option	
AD8522AN	-40°C to +85°C	14-Pin P-DIP	N-14	
AD8522AR	-40°C to +85°C	14-Lead SOIC	SO-14	

The AD8522 contains 1482 transistors.

#### CAUTION.

ESD (electrostatic discharge) sensitive device. Electrostatic charges as high as 4000 V readily accumulate on the human body and test equipment and can discharge without detection. Although the AD8522 features proprietary ESD protection circuitry, permanent damage may occur on devices subjected to high energy electrostatic discharges. Therefore, proper ESD precautions are recommended to avoid performance degradation or loss of functionality.



#### **OPERATION**

The AD8522 is a complete ready-to-use dual 12-bit digital-to-analog converter. Only one +5 V power supply is necessary for operation. It contains two voltage-switched, 12-bit, laser-trimmed digital-to-analog converters, a curvature-corrected bandgap reference, rail-to-rail output op amps, input registers, and DAC registers. The serial data interface consists of a serial data input (SDI), clock (CLK), and two load strobe pins ( $\overline{LDA}$ ,  $\overline{LDB}$ ) with an active low  $\overline{CS}$  strobe. In addition, an asynchronous  $\overline{RS}$  pin will set all DAC register bits to zero causing the  $V_{OUT}$  to become zero volts, or to midscale for trimming applications when the MSB pin is programmed to Logic 1. This function is useful for power on reset or system failure recovery to a known state.

#### D/A CONVERTER SECTION

The internal DAC is a 12-bit voltage-mode device with an output that swings from AGND potential to the 2.5 V internal bandgap voltage. It uses a laser-trimmed R-2R ladder which is switched by N channel MOSFETs. The output voltage of the DAC has a constant resistance independent of digital input code. The DAC output is internally connected to the rail-to-rail output op amp.

#### AMPLIFIER SECTION

The internal DAC's output is buffered by a low power consumption precision amplifier. This low power amplifier contains a differential PNP pair input stage that provides low offset voltage and low noise, as well as the ability to amplify the zero-scale DAC output voltages. The rail-to-rail amplifier is configured in a gain of  $1.638 \ (= 4.095\ V/2.5\ V)$  in order to set the  $4.095\ V$  full-scale output (1 mV/LSB). See Figure 4 for an equivalent circuit schematic of the analog section.

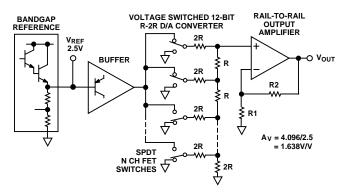


Figure 4. Equivalent AD8522 Schematic of Analog Portion

The op amp has a  $16~\mu s$  typical settling time to 0.01%. There are slight differences in settling time for negative slewing signals versus positive. See the oscilloscope photos in the "Typical Performance Characteristics" section of this data sheet.

#### **OUTPUT SECTION**

The rail-to-rail output stage of this amplifier has been designed to provide precision performance while operating near either power supply. Figure 5 shows an equivalent output schematic of the rail-to-rail amplifier with its N channel pull-down FETs that will pull an output load directly to GND. The output sourcing current is provided by a P channel pull-up device that can supply GND terminated loads, especially important at the -10% supply tolerance value of 4.5 V.

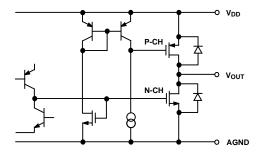


Figure 5. Equivalent Analog Output Circuit

Figures 6 and 7 in the typical performance characteristics section provide information on output swing performance near ground and full scale as a function of load. In addition to resistive load driving capability the amplifier has also been carefully designed and characterized for up to 500 pF capacitive load driving capability.

#### REFERENCE SECTION

The internal 2.5 V curvature-corrected bandgap voltage reference is laser trimmed for both initial accuracy and low temperature coefficient. The voltage generated by the reference is available at the  $V_{\rm REF}$  pin. Since  $V_{\rm REF}$  is *not* intended to drive heavy external loads, it must be buffered. The equivalent emitter follower output circuit of the  $V_{\rm REF}$  pin is shown in Figure 4.

Bypassing the  $V_{\text{REF}}$  pin will improve noise performance; however, bypassing is not required for proper operation. Figure 10 shows broad band noise performance.

#### **POWER SUPPLY**

The very low power consumption of the AD8522 is a direct result of a circuit design optimizing use of a CBCMOS process. By using the low power characteristics of the CMOS for the logic, and the low noise, tight matching of the complementary bipolar transistors good analog accuracy is achieved.

For power consumption sensitive applications it is important to note that the internal power consumption of the AD8522 is strongly dependent on the actual input voltage levels present on the SDI, CLK,  $\overline{\text{CS}}$ , MSB,  $\overline{\text{LDA}}$ ,  $\overline{\text{LDB}}$  and  $\overline{\text{RS}}$  pins. Since these inputs are standard CMOS logic structures, they contribute static power dissipation dependent on the actual driving logic  $V_{OH}$  and  $V_{OL}$  voltage levels. Consequently for optimum dissipation use of CMOS logic versus TTL provides minimal dissipation in the static state. A  $V_{\rm INL}=0$  V on the logic input pins provides the lowest standby dissipation of 1 mA with a +5 V power supply.

As with any analog system, it is recommended that the AD8522 power supply be bypassed on the same PC card that contains the chip. Figure 12 shows the power supply rejection versus frequency performance. This should be taken into account when using higher frequency switched-mode power supplies with ripple frequencies of 100 kHz and higher.

One advantage of the rail-to-rail output amplifiers used in the AD8522 is the wide range of usable supply voltage. The part is fully specified and tested over temperature for operation from  $+4.5~\rm V$  to  $+5.5~\rm V$ . If reduced linearity and source current capability near full scale can be tolerated, operation of the AD8522

REV. A -5-

### AD8522

is possible down to +4.3 V. The minimum operating supply voltage versus load current plot, in Figure 7, provides information for operation below  $V_{\rm DD}=+4.5~\rm V.$ 

#### TIMING AND CONTROL

The AD8522 has a 16-bit serial input register that accepts clocked in data when the CS pin is active low. The DAC registers are updated by the Load Enable ( $\overline{\text{LDA}}$  and  $\overline{\text{LDB}}$ ) pins.

The AD8522 offers two modes of data loading. The first mode, hardware-load, directs the data currently clocked into the serial shift register into either the DAC A or the DAC B register or both depending on the external active low strobing of the  $\overline{LDA}$  or  $\overline{LDB}$  pin. Serial data register bit Sf/ $\overline{Hd}$  must be low for this mode to be in effect.

The second mode of operation is software-load which is designed to minimize the number of control lines connected to the AD8522. In this mode of operation the  $\overline{LDA}$  and  $\overline{LDB}$  pins act as one control input taking the present contents of the serial

input register and transferring the 12 bits of data into the decoded address determined by the address bits A and B in the serial input register.

#### **Unipolar Output Operation**

This is the basic mode of operation for the AD8522. The AD8522 has been designed to drive loads as low as 820  $\Omega$  in parallel with 500 pF. The code table for this operation is shown in Table III.

**Table III. Unipolar Code Table** 

Hexadecimal Number in DAC Register	Decimal Number in DAC Register	Analog Output Voltage (V)		
FFF	4095	+4.095		
801	2049	+2.049		
800	2048	+2.048		
7FF	2047	+2.047		
000	0	0		

## **Typical Performance Characteristics**

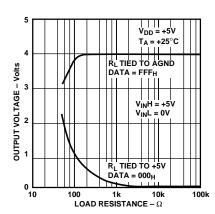


Figure 6. Output Swing vs. Load

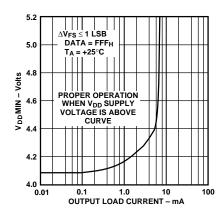


Figure 7. Minimum Supply Voltage vs. Load Current

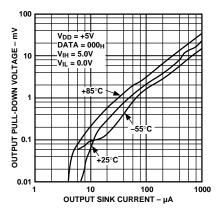


Figure 8. Pull-Down Voltage vs. Output Sink Current Capability

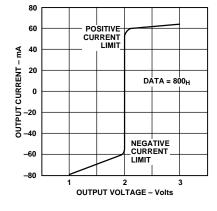


Figure 9.  $I_{OUT}$  vs.  $V_{OUT}$ 

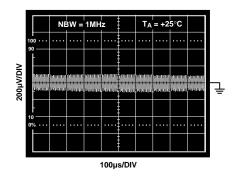


Figure 10. Broadband Noise

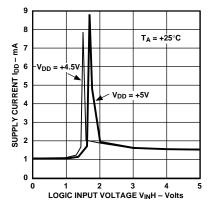
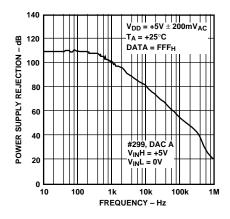
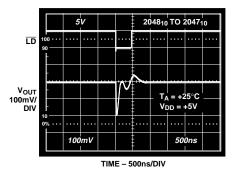


Figure 11. Supply Current vs. Logic Input Voltage





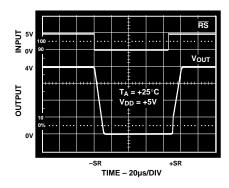
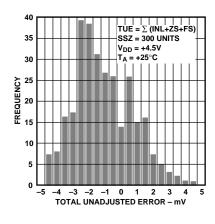
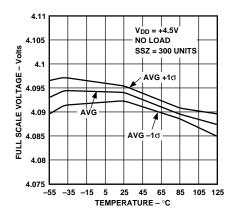


Figure 12. Power Supply Rejection vs. Frequency

Figure 13. Midscale Transition Performance

Figure 14. Large Signal Settling Time





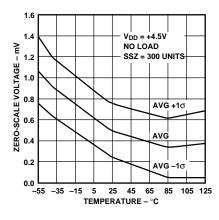
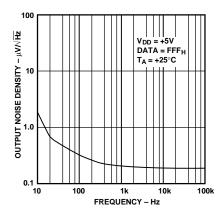
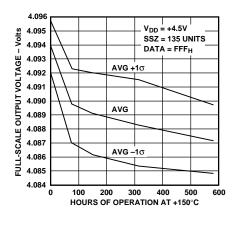


Figure 15. Total Unadjusted Error Histogram

Figure 16. Full-Scale Voltage vs. Temperature

Figure 17. Zero-Scale Voltage vs. Temperature





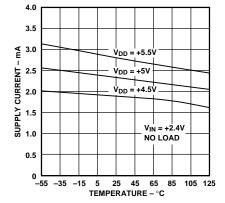
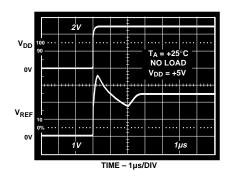


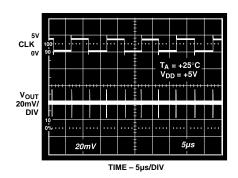
Figure 18. Output Voltage Noise Density vs. Frequency

Figure 19. Long Term Drift Accelerated by Burn-In

Figure 20. Supply Current vs. Temperature

REV. A -7-





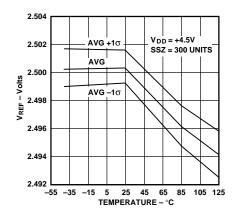
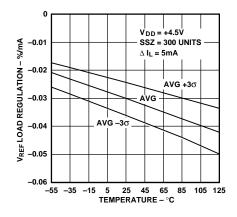
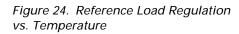


Figure 21. Reference Startup vs. Time

Figure 22. Digital Feedthrough vs. Time

Figure 23. Reference Voltage vs. Temperature





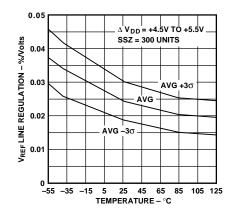
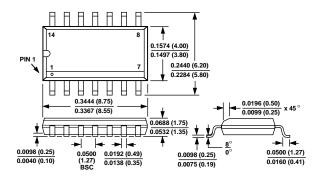


Figure 25. Reference Line Regulation vs. Temperature

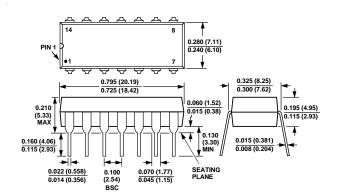
#### **OUTLINE DIMENSIONS**

Dimensions shown in inches and (mm).

#### 14-Lead Narrow Body SOIC (SO-14)



#### 14-Lead Epoxy DIP (N-14)



#### **ПОСТАВКА** ЭЛЕКТРОННЫХ КОМПОНЕНТОВ

Общество с ограниченной ответственностью «МосЧип» ИНН 7719860671 / КПП 771901001 Адрес: 105318, г.Москва, ул.Щербаковская д.3, офис 1107

## Данный компонент на территории Российской Федерации Вы можете приобрести в компании MosChip.

Для оперативного оформления запроса Вам необходимо перейти по данной ссылке:

#### http://moschip.ru/get-element

Вы можете разместить у нас заказ для любого Вашего проекта, будь то серийное производство или разработка единичного прибора.

В нашем ассортименте представлены ведущие мировые производители активных и пассивных электронных компонентов.

Нашей специализацией является поставка электронной компонентной базы двойного назначения, продукции таких производителей как XILINX, Intel (ex.ALTERA), Vicor, Microchip, Texas Instruments, Analog Devices, Mini-Circuits, Amphenol, Glenair.

Сотрудничество с глобальными дистрибьюторами электронных компонентов, предоставляет возможность заказывать и получать с международных складов практически любой перечень компонентов в оптимальные для Вас сроки.

На всех этапах разработки и производства наши партнеры могут получить квалифицированную поддержку опытных инженеров.

Система менеджмента качества компании отвечает требованиям в соответствии с ГОСТ Р ИСО 9001, ГОСТ РВ 0015-002 и ЭС РД 009

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